





## **S1Y General Purpose Rectifier**



#### **Features**

- Glass passivated die construction
- High surge current capability
- Cases: Molded plastic
- MSL is level One
- Terminals finish: Tin Lead-free plated
- This is a Pb Free device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

Rectifier

### Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic	Symbol	S1Y	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	2000	V
Maximum RMS voltage	$V_{RMS}$	1400	V
Average Rectified Output Current 60HZ Half-sine wave, Resistance load, T∟=130℃	lo	1	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	25	А
Forward Voltage* @ I <sub>F</sub> = 1.0 A	V <sub>F</sub>	1.2	V
Peak Reverse Current* @T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @T <sub>A</sub> = 125°C	I <sub>RM</sub>	5 200	μA
Typical Junction Capacitance(Note1)	Сл	14	pF
Typical Thermal Resistance Junction to Lead (Note 2)	R <sub>θJL</sub>	22	°C/W
Typical Thermal Resistance Junction to Ambient (Note 2)	R <sub>θJA</sub>	95	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150	°C

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" ( 5.0 mm x 5.0 mm) copper pad areas.

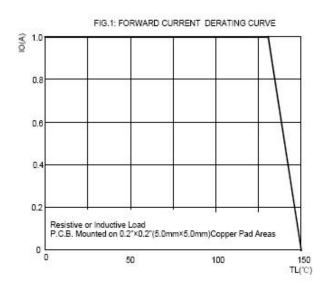
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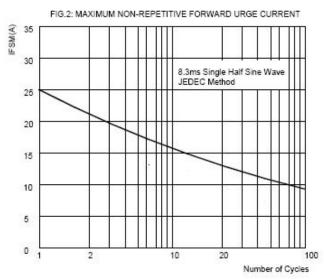


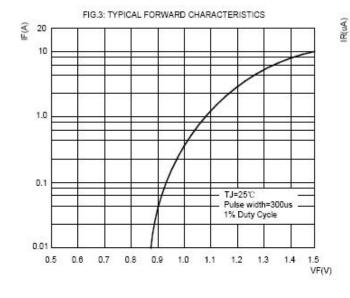


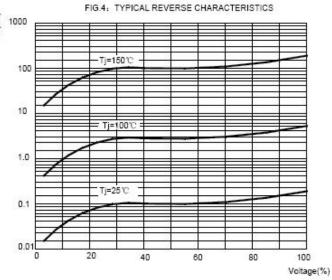


# **Ratings and Characteristics Curves**









<sup>•</sup> China - Germany - Korea - Singapore - United States •

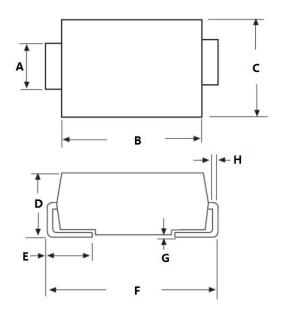
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### **Mechanical Dimensions SMA**



CVMDOL	Millimeters		Inches	
SYMBOL	Min.	Max.	Min.	Max.
А	1.25	1.65	0.049	0.065
В	3.95	4.60	0.156	0.181
С	2.25	2.95	0.089	0.116
D	1.95	2.90	0.077	0.114
E	0.75	1.60	0.030	0.063
F	4.80	5.60	0.189	0.220
G	0.05	0.20	0.002	0.008
Н	0.15	0.41	0.006	0.016

## **Ordering Information**

Device	Package	Shipping	
S1Y	SMA(Pb-Free)	5000pcs / reel	
S1YTR	SMA(Pb-Free)	5000pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**

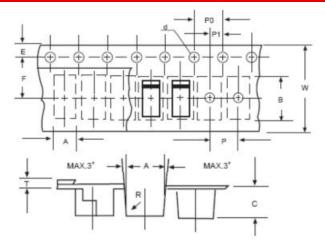


Where XXXXX is YYWWL

S = Device Type
1 = Forward Current (1A)
Y = Reverse Voltage (2000V)
YY = Year
WW = Week

= Lot Number

### **Carrier Tape Specification SMA**



SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
C	2.32	2.52	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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